

TA-E88 / E88B



TA-E88 (Panel: Silver)
AEP Model

TA-E88B (Panel: Black)
AEP Model
UK Model

STEREO PREAMPLIFIER

SPECIFICATIONS

GENERAL

Power
Requirements: 240 V ac, 50/60 Hz (UK)
220 V ac, 50/60 Hz (AEP)

Power Consumption: 22 W

Dimensions: Approx. 480 (w) x 80 (h) x 370 (d) mm
19 (w) x 3 1/8 (h) x 14 5/8 (d) inches
Including projecting parts and controls

Weight: Approx. 9.4 kg, 20 lb 12 oz (net)
9.7 kg, 21 lb 7 oz (with shipping carton)

AMPLIFIER SECTION

Inputs:

	Sensitivity	Impedance	Capacitance	Maximum input capability (1 kHz)	S/N (weighting network, input level)
PHONO 1	2.5 mV (-50 dB)	50 kΩ	100 pF	250 mV (-10 dB)	88 dB (A, 2.5 mV)
HEAD AMP	0.125 mV (-76 dB)	25Ω/100Ω	-	12.5 mV (-36 dB)	80 dB (A, 0.2 mV)
PHONO 2	2.5 mV (-50 dB)	10 kΩ-100 kΩ (10 kΩ steps)	100 pF-500 pF (100 pF steps)	250 mV (-10 dB)	88 dB (A, 2.5 mV)
HEAD AMP	0.125 mV (-76 dB)	25Ω/100Ω	-	12.5 mV (-36 dB)	80 dB (A, 0.2 mV)
TUNER, AUX TAPE 1, 2	150 mV (-14.5 dB)	50 kΩ	-	-	105 dB (A, 150 mV)

SAFETY-RELATED COMPONENT WARNING !!

COMPONENTS IDENTIFIED BY SHADING AND MARK ON THE SCHEMATIC DIAGRAMS, EXPLODED VIEWS AND IN THE PARTS LIST ARE CRITICAL TO SAFE OPERATION. REPLACE THESE COMPONENTS WITH SONY PARTS WHOSE PART NUMBERS APPEAR AS SHOWN IN THIS MANUAL OR IN SUPPLEMENTS PUBLISHED BY SONY.

TA-E88 / E88B

MODEL IDENTIFICATION Specification Label



TA-E88 (AEP Model)



TA-E88B (AEP Model)

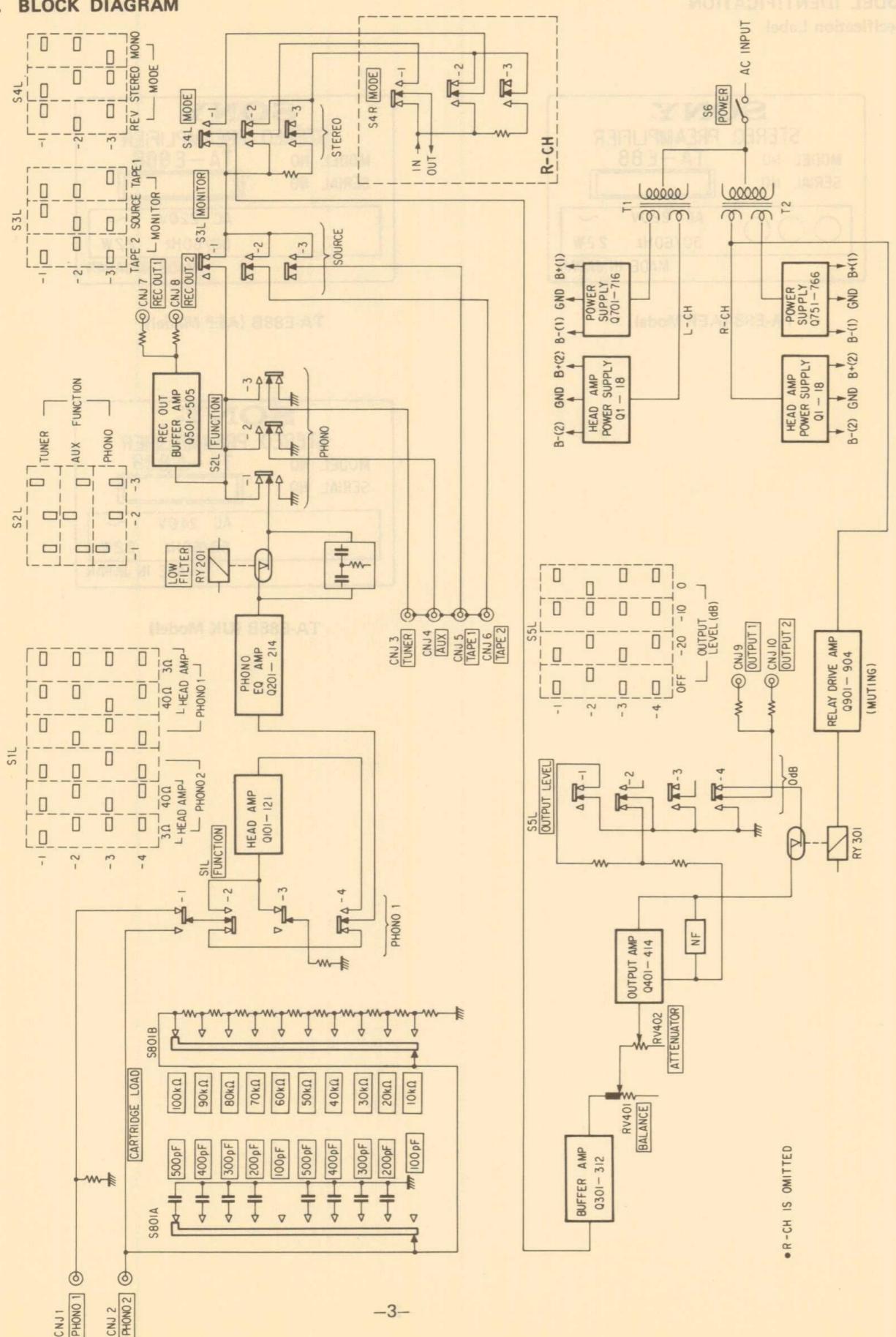


TA-E88B (UK Model)

SONY®
SERVICE MANUAL

SECTION 1 OUTLINE

1-1. BLOCK DIAGRAM



1-2. CIRCUIT DESCRIPTION

1-2-1. Phono 1 and Phono 2 Input Circuits

The TA-E88/E88B is equipped with two phono inputs – PHONO 1 and PHONO 2.

PHONO 1

- When using high impedance cartridges (output about 2.5mV):

When the FUNCTION switch (S1) is set to the PHONO 1 position, the input impedance Z_{in1} ($150k\Omega$, $100pF$) of equalizer amplifier is connected in parallel with R1 ($75k\Omega$) across the PHONO 1 input terminal. They serve as load impedance for the cartridge used.
($R = 50k\Omega$, $C = 100pF$)

- When using low impedance MC cartridges (output about $125\mu V$):

The head amplifier is connected by switching S1. At the same time, either a 3Ω or 40Ω load impedance (depending on cartridge impedance) is also connected to the PHONO 1 input terminal. For the load of 40Ω cartridge, the input impedance Z_{in2} (100Ω) of head amplifier is employed, and for the load of 3Ω cartridge R2 (33Ω) is connected in parallel with Z_{in1} , resulting in a 25Ω input resistance.

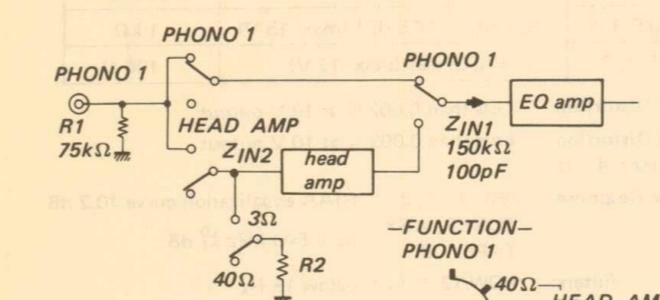


Fig. 1

PHONO 2

- The PHONO 2 input is basically the same as the PHONO 1 input, but also is equipped with a

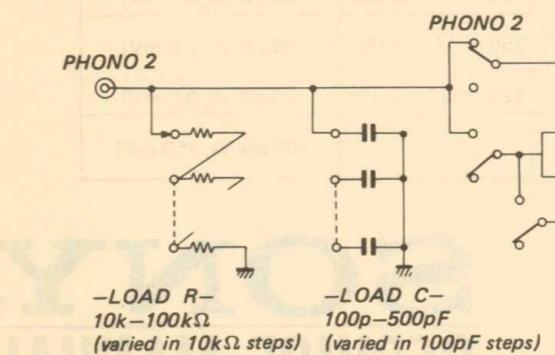


Fig. 2

cartridge load selector. It is adjustable over $10k\Omega$ to $100k\Omega$ and $100pF$ to $500pF$ ranges when using high impedance cartridge.

- This switch (S801) located on the top case is a kind of rotary switch.

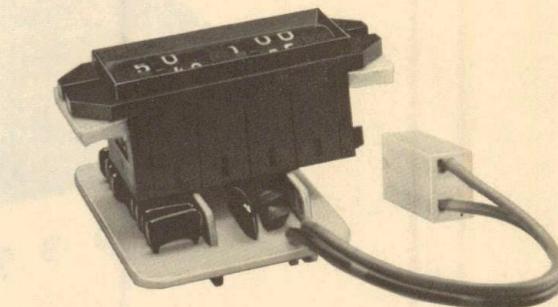


Fig. 3

1-2-2. Head Amplifier

Generally, the very low level signals produced by an MC (moving coil) cartridge are amplified by step-up transformer.

On the other hand, in the TA-E88/TA-E88B, this amplification is performed by a built-in head amplifier. Although the use of active amplification elements (rather than passive transformers) causes some deterioration of S/N ratio, these problems have been successfully overcome in the TA-E88/E88B by employing parallel-connected transistors in the head amplifier.

The head amplifier includes a main amplifier stage consisting of eight transistors (Q101 to Q108) connected in parallel, and another eight transistors (Q109 to Q116) differentially-connected to this main stage, achieving gain of 27dB with usually-low noise.

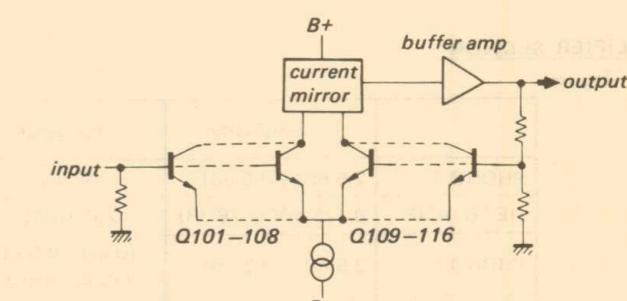


Fig. 4

• Parallel Connection

When a transistor is used for amplification purposes, the current flowing between the collector and emitter of the active transistor is placed under control. Signals from the base terminal pass through the internal resistance of the base spread

resistance r_{bb}' . (This base spread resistance is one of the critical factors which have to be considered in high frequency amplification). The detailed diagram is shown in Fig. 5.

The lower the r_{bb}' resistance, the less the noise will become. This may be achieved by connecting transistors in parallel – n transistors connected in parallel reduce noise by $1/\sqrt{n}$.

This may also be considered as parallel-connected transistor collectors (noise output terminals), resulting in the averaging out of noise levels and phase differences of the noise elements in each transistor.

collector

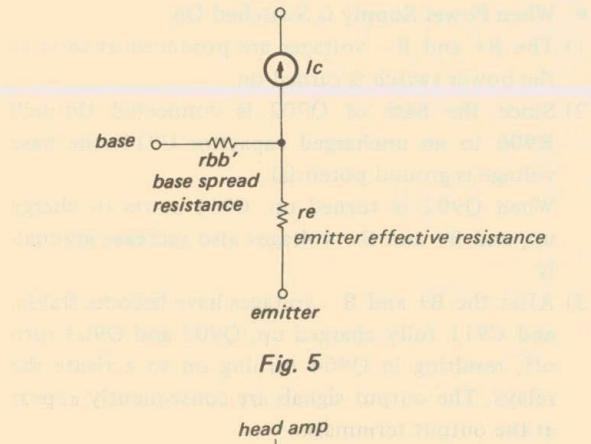


Fig. 5

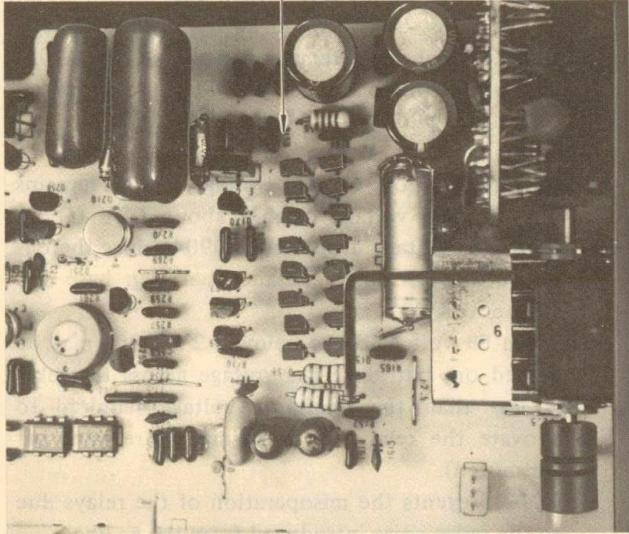


Fig. 6

1-2-3. Equalizer Amplifier

The phono equalizer amplifier stage consists of Q201 through Q214. In order to design the TA-E88/E88B as a direct-coupled dc amplifier, this stage includes the following features:

- An FET in the first stage

- The Miller effect by caused internal capacitance between drain and gate of FET in the first stage results in deterioration of high end frequency response due to high input impedance. To prevent this, the drain of FET in the first stage is connected to the source of the following low input impedance transistor (Q202).

The impedance of the equalizer components (R228 to R230) is kept low to further improve the S/N ratio. The equalizer amplifier output stage employed to drive these components consists of a 2-stage emitter-follower push-pull circuit. A dual transistor, featuring two pairs of elements mounted on a single wafer, is used to improve the thermal and pair characteristics for differential operation of Q201, Q202 and Q205.

1-2-4. Buffer Amplifier

The buffer amplifier (Q301 to Q312) up to the equalizer amplifier has a gain of 0dB. That is, there is 100% negative feedback of the output voltage from the output terminal to the input negative feedback terminal.

This amplifier is used to drive BALANCE control and ATTENUATOR.

Frequency response deterioration will occur if high-value resistors are used in the step attenuator. The TA-E88/E88B employs low resistance resistors ($3k\Omega$). This also results in decreased thermal noise. A buffer amplifier is used to drive the low resistance BALANCE control and ATTENUATOR. This amplifier uses a differential-cascode amplifier in the first stage. Fig. 8 shows the location of the FET.



Fig. 7

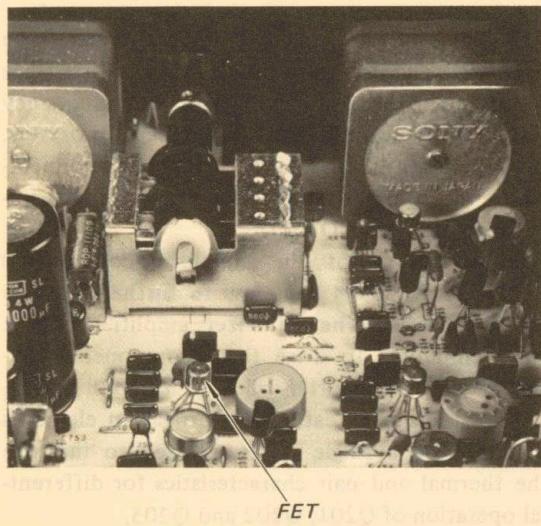


Fig. 8

1-2-5. Output Amplifier

The output amplifier consists of Q401 to Q414. It amplifies signals from dc to high frequency and drives OUTPUTS 1 and 2 of TA-E88/E88B. Generally, an output amplifier must be capable of delivering high-level, low-impedance output signals to match a wide range of power amplifiers. For this reason, the TA-E88/E88B is designed to supply an output signal up to 15Vrms with 100Ω output impedance.

This amplifier stage is also equipped with the OUTPUT LEVEL switch (S5) to permit the output level to be varied in 10dB steps.

The four selector positions are 0dB, -10dB, -20dB and OFF.

1-2-6. Power Supply

Both left and right channels have independent power supplies which produce the +42V and -42V for B voltage, plus the +14V and -14V for the head amplifier.

Power supply circuit for head amplifier consists of Q1 to Q18. (mounted on head amp power supply board

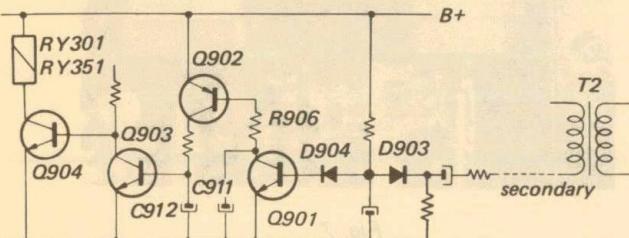


Fig. 9

located near the main board). The reason for positioning this power supply as close as possible to the head amplifier is to prevent the introduction of extraneous noise on the B+ and B- bus.

1-2-7. Relay Drive Amplifier

This amplifier, consisting of Q901 to Q904 (mounted on the rectifier board), drives the muting relays RY301 and RY351. These muting relays operate when the power supply switch is turned on and off. The signal path is completed when these relays are turned on under the condition described below. The simplified relay drive amplifier circuit is shown in Fig. 9.

• When Power Supply is Switched On

- 1) The B+ and B- voltages are produced as soon as the power switch is turned on.
- 2) Since the base of Q902 is connected through R906 to an uncharged capacitor C911, the base voltage is ground potential. When Q902 is turned on, C911 starts to charge up, and B+ and B- voltages also increase gradually.
- 3) After the B+ and B- voltages have become stable, and C911 fully charged up, Q902 and Q903 turn off, resulting in Q904 turning on to activate the relays. The output signals are consequently appear at the output terminals.

• When Power Supply is Switched Off

- 1) As soon as the POWER switch is turned off, Q901 (which had remained off due to D903) and Q902 turn on, and then Q903 also turns on. Therefore, Q904 (for relay drive) turns off.
- 2) Although both B+ and B- voltages commence to rapidly drop to zero voltage, Q901 remains on until B+ voltage reaches about 1.2V (Q901 V_{BE} plus voltage drop across D904) since there is no voltage dividing resistance between base and emitter of Q901.
- 3) When B+ voltage drops below 1.2V, Q904 may be turned on, but since the voltage across the relay is less than the minimum voltage required to activate the relay, the relay simply remains off (or muted).
- 4) C912 prevents the misoperation of the relays due to the pulse noise introduced from the ac line.

1-2-8. REC OUT Buffer Amplifier

The REC OUT terminals provide fixed level output signals from the REC OUT buffer amplifier stage (Q501 to Q505) between the equalizer amplifier and buffer amplifier.

1-2-9. Overall Amplifier

Although the TA-E88/E88B consists of ten dc amplifier stages, all of these stages are basically the same. The output amplifier is described here as an example of one of these stages.

Fig. 11 shows the relevant signal levels when S5 is set to 0dB, and the input level is adjusted to obtain an output level of about 0dBrms (2.2Vp-p). The + and - signs refer to the signal polarity at that point. However, the (-) sign on the right hand gate (NFB input) of the first stage Q401 indicates that this was originally a negative polarity.

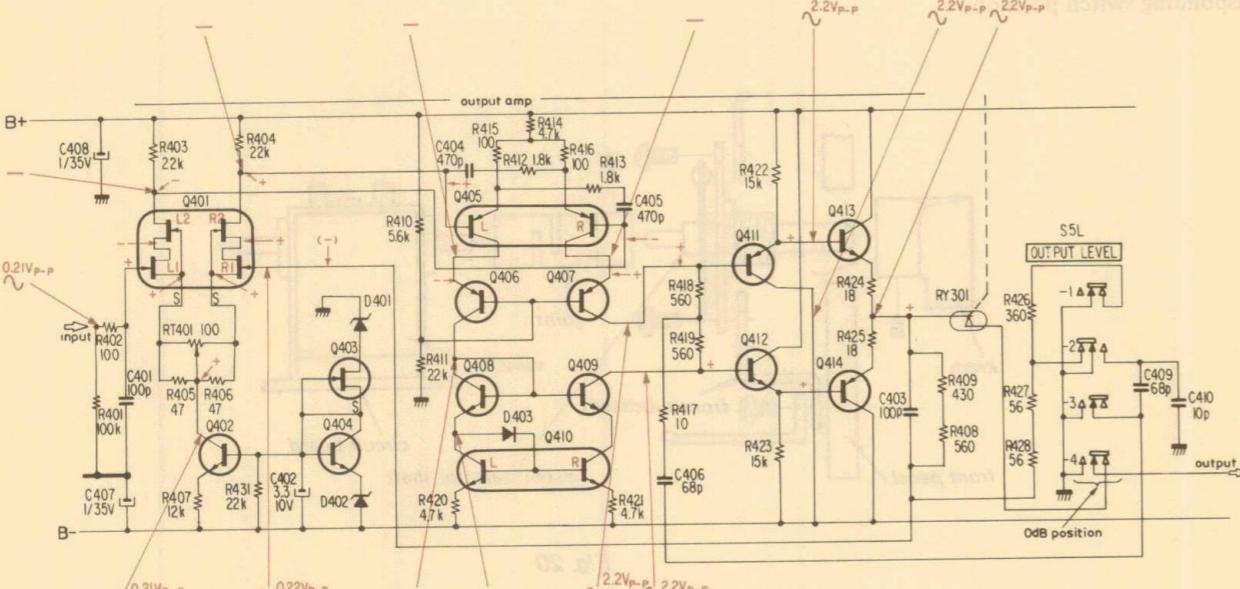


Fig. 11

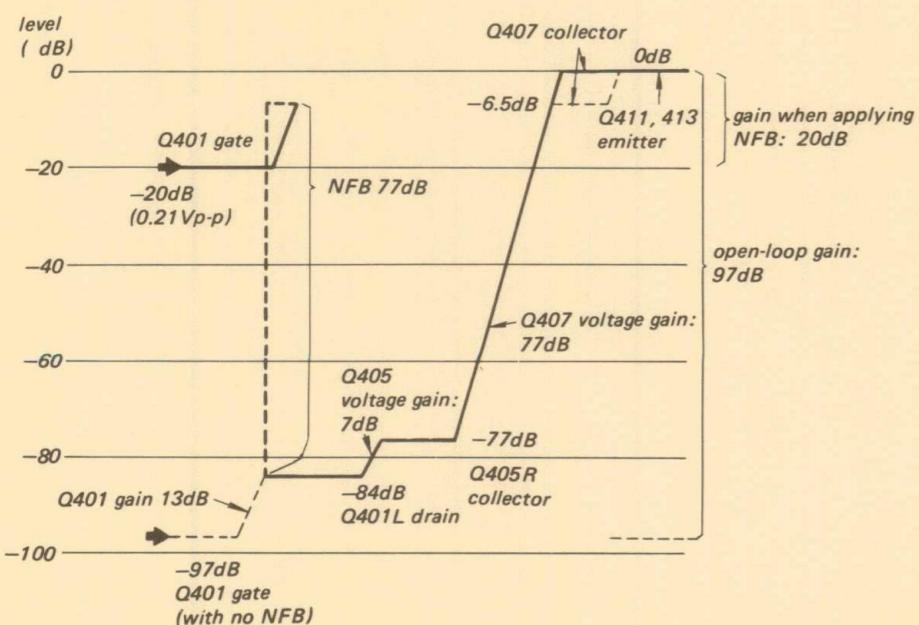


Fig. 12

Circuit Description

- When observing the signal levels, the 0.2Vp-p (about -20dB) input signal applied to the gate of

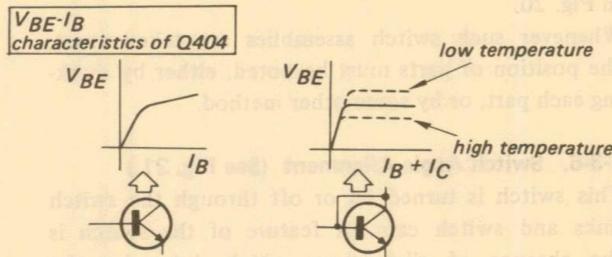


Fig. 10

Q401 is not measured at the drain of Q401 (L2). However, 2.2Vp-p (about 0dB) signal appears at the collector of Q407, and is extracted from the emitter follower.

- The level diagram is shown in Fig. 12. An NFB of 77dB is applied to the amplifier which has 97dB open-loop gain. Since the gain of an NFB amplifier is reduced only by the amount of NFB applied to that stage, the level at the drain of the Q401 becomes -84dB. This is the reason why the signal level is too low to be measured at the intermediate points of amplifier.

- D401, Q403, Q404 and D402 form a thermally-compensated constant voltage circuit, which operates as follows (the voltages referred to here are relative to the B- voltage): D402 (EQB01-05) is a 5V zener diode which maintains the emitter of Q404 at +5V level. To obtain a flat base voltage (V_{BE}) from the collector of Q404, the base and collector are connected as shown in Fig. 10. The characteristics referring to this connection are also shown in Fig. 10.

When the value of V_{BE} reaches the "shoulder" of the curve, it suddenly becomes constant, and subsequently varies only with changes of temperature. Any temperature-related variations in V_{BE} of Q404 are fed to Q402, but since Q402 and Q404 are identical transistors, these variations are automatically compensated for by the other transistor. Hence, Q402 and Q404 serve to compensate for any voltage variations caused by changes of temperature.

- Q403 is a 2SK42 N-channel depression type FET. As shown in Fig. 13, EG = ES when gate and source are connected, resulting in the flow of a constant current of less than 5mA.

In other words, Q403 serves as the load resistance for Q402.

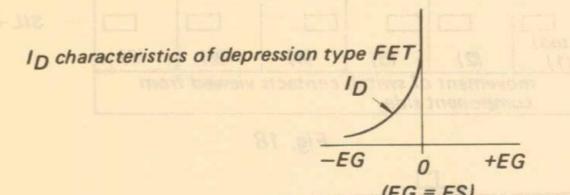


Fig. 13

- Q402 has an emitter resistor with sufficiently high resistance to obtain constant base voltage, which means that the emitter current (collector current) always remains constant. A bipolar transistor type constant current circuit such as this can provide highly-constant current at low supply voltages.
- Q401 is a cascode connection with the polarity from the lower gate to the upper drain as shown

in Fig. 11.

- Q405, Q406 and Q407 form the second cascode-connection differential amplifier. Q408, Q409 and Q410 (current-mirror circuit) serve as the load resistance for Q406 and Q407. The output from this differential amplifier appears single-ended at the collector of Q407, while the signal on the collector of Q406 is passed from Q408, Q410 to Q409. Q407 and Q409 drive Q411 and Q412. Furthermore, although Q409 also operates as a constant current circuit, and the Q407 collector current is passed through R418 and R419 to Q411 and Q412, signals of almost equal amplitude are passed to these two transistors (Q411 and Q412).

In addition, the thermal compensation for Q410R and Q409 is achieved by Q410L and Q408.

- Q411, Q412, Q413 and Q414 form a cross-coupled current driver circuit, comprising pairs of NPN, PNP emitter-followers.

CAUTION

The transistors have a resistor to their collector or emitter circuits. These transistors will be not damaged if any of transistor terminals are short-circuited. The exception is Q403 which supplies constant current to D401, Q404 and D402. If the drain and source of Q403 are short-circuited, D401, Q403, Q404 and D402 will be completely destroyed.

1-3. Parts Information**1-3-1. Small Resistors**

The TA-E88/E88B uses many small resistors, similar to the type shown in Fig. 14. These resistors are $\frac{1}{4}W$ metal-oxide with an accuracy of 1%. Note that this accuracy rating has been omitted in the schematic diagrams. (The $\frac{1}{4}W$ and $\frac{1}{2}W$ carbon resistor accuracy ratings are indicated).

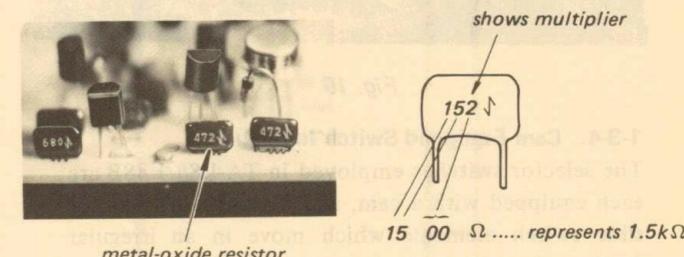


Fig. 14

1-3-2. Square Tantalum Capacitors

The capacitors employed in the TA-E88/E88B (as shown in Fig. 15) are the same square tantalum capacitors used in pulse circuit power supplies, etc. These capacitors are especially used in the B+ and B- bus where their greater by-pass effect is needed.

square tantalum capacitor

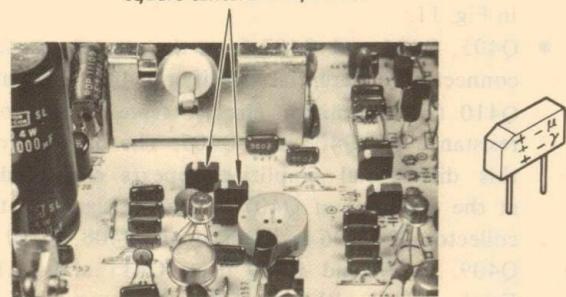


Fig. 15

1-3-3. Mounting of Components

When mounting the components on the circuit board, take care that they do not touch the shafts of switches, variable resistors, etc. Be particularly careful to prevent any contact between the compound FET covered by metal case, and the ATTEN-ATOR shaft, and the diode leads and BALANCE control shaft.

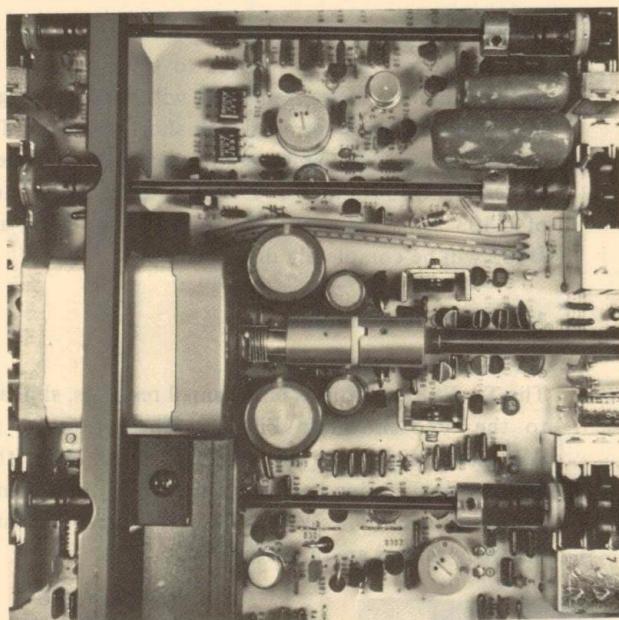


Fig. 16

1-3-4. Cam Equipped Switch Indication

The selector switches employed in TA-E88/E88B are each equipped with a cam, and a number (3 or 4) of slide switch elements which move in an irregular fashion when the cam rotates.

As an example of this arrangement, S1L (FUNCTION PHONO INPUT) is shown in Fig. 17.

There are a total of ten switches employed in the TA-E88/E88B, making it impossible to determine which points are making contact at different select positions. For this reason, both the schematic diagram and the mounting diagram include special charts of the contact patterns for each switch position.

Note that these charts indicate the position of the blue switch link heads as viewed from the component side, thereby simplifying checking operations as well.

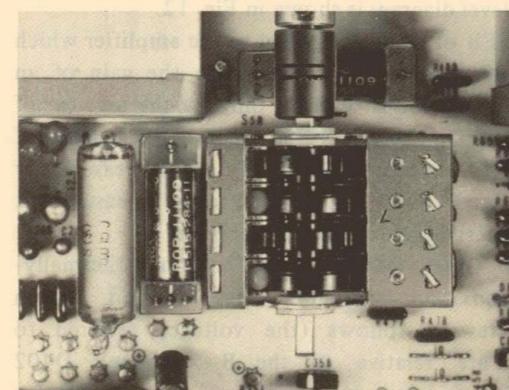


Fig. 17

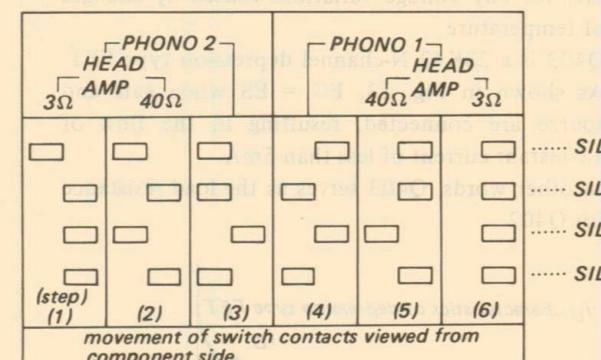
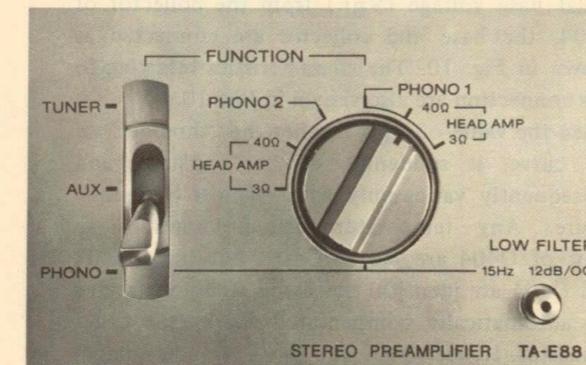


Fig. 18

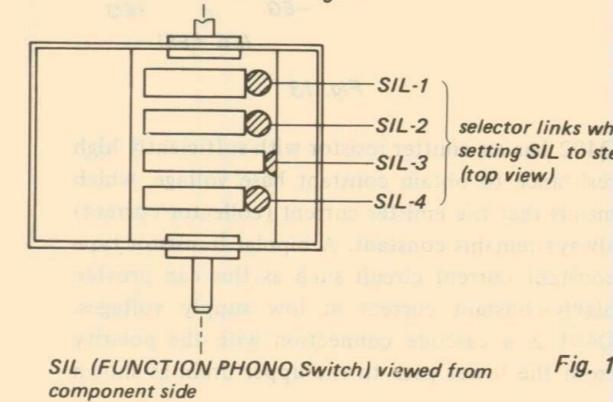


Fig. 19

1-3-5. Order of Parts in Switch Assemblies

A typical switch assembly, including the switch, the joint, front panel and selector knob, is shown in Fig. 20.

Whenever such switch assemblies are taken apart, the position of parts must be noted, either by marking each part, or by some other method.

1-3-6. Switch Angle Alignment (See Fig. 21.)

This switch is turned on or off through the switch links and switch cam. A feature of the switch is the absence of click stops which determine the actual switching position. Therefore, it is necessary to correctly align the selector knob precisely with its corresponding switch position.

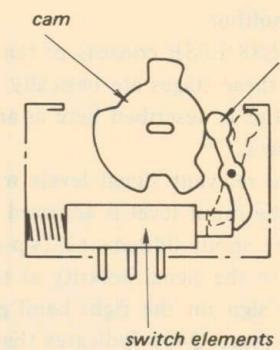


Fig. 21

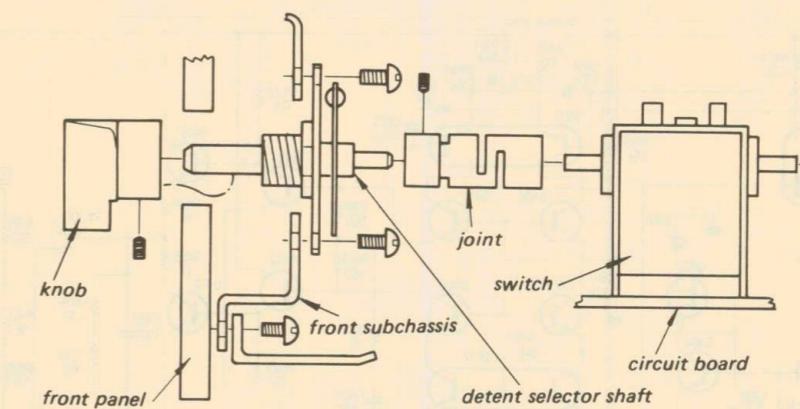
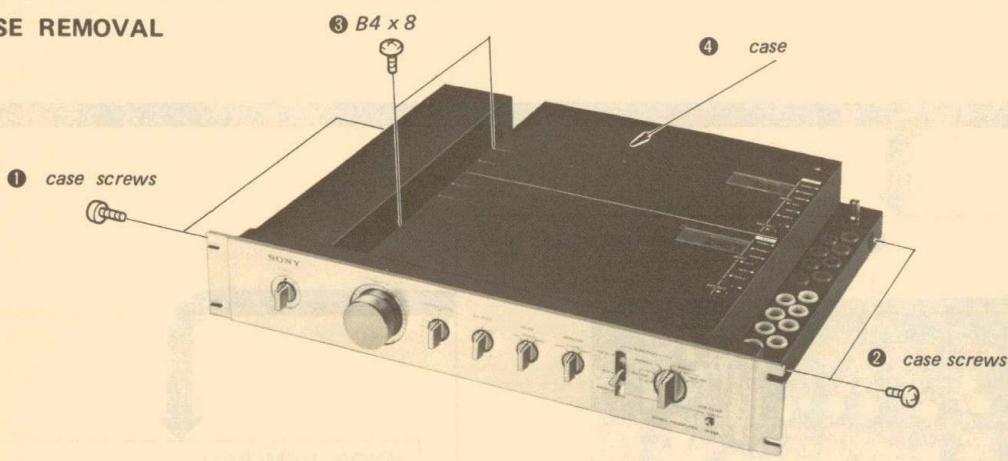


Fig. 20

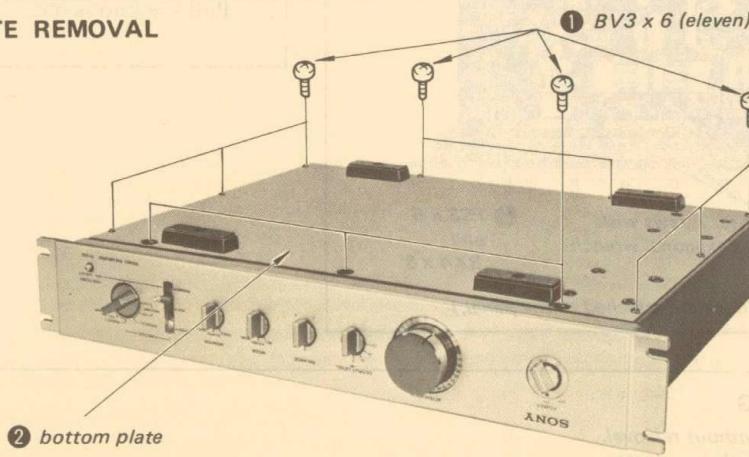
SECTION 2 DISASSEMBLY

Note: Follow the disassembly procedure in the numerical order given.

CASE REMOVAL



BOTTOM PLATE REMOVAL



ATTENUATOR KNOB REMOVAL

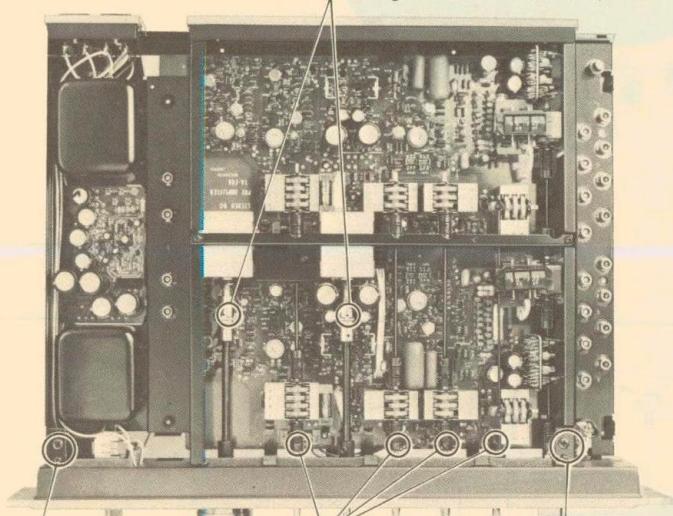
- ① Loosen the set screw with an L-shaped hexagonal wrench (1.5mm)



Note: Other knobs can be removed after the panel removal.

TA-E88/E88B**PANEL REMOVAL**

- 1 Loosen two set screws with an L-shaped hexagonal wrench (1.5mm)



③ PS3 x 6 and
RK4 x 8

② Loosen four set screws with
an L-shaped hexagonal wrench
(1.5mm).

④ PS3 x 6
and
RK4 x 8

- 5 Pull the panel out. (Knobs are attached to the panel.)

KNOB REMOVAL

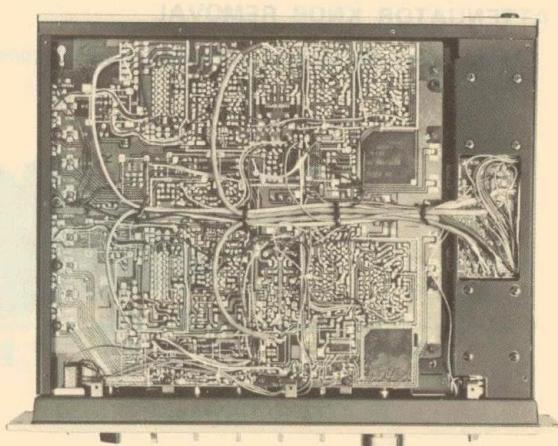
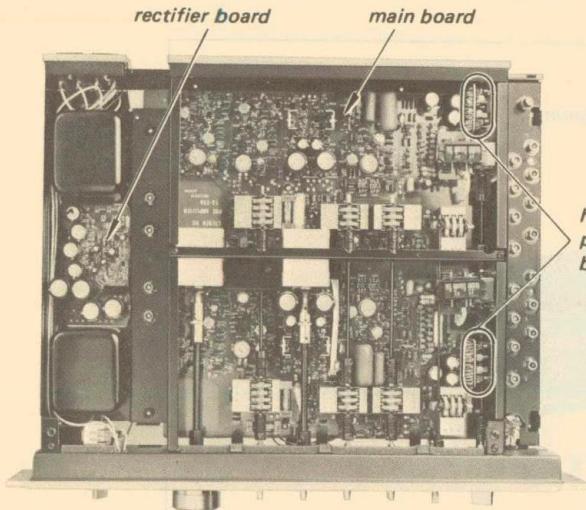
- 1 Loosen the set screws with an L-shaped hexagonal wrench (1.5mm) from the bottom side of the panel.
- 2 Pull the knobs out.

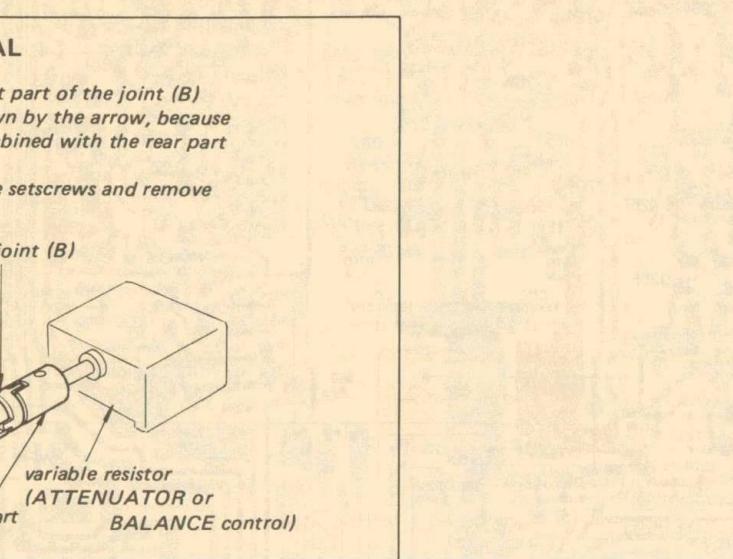
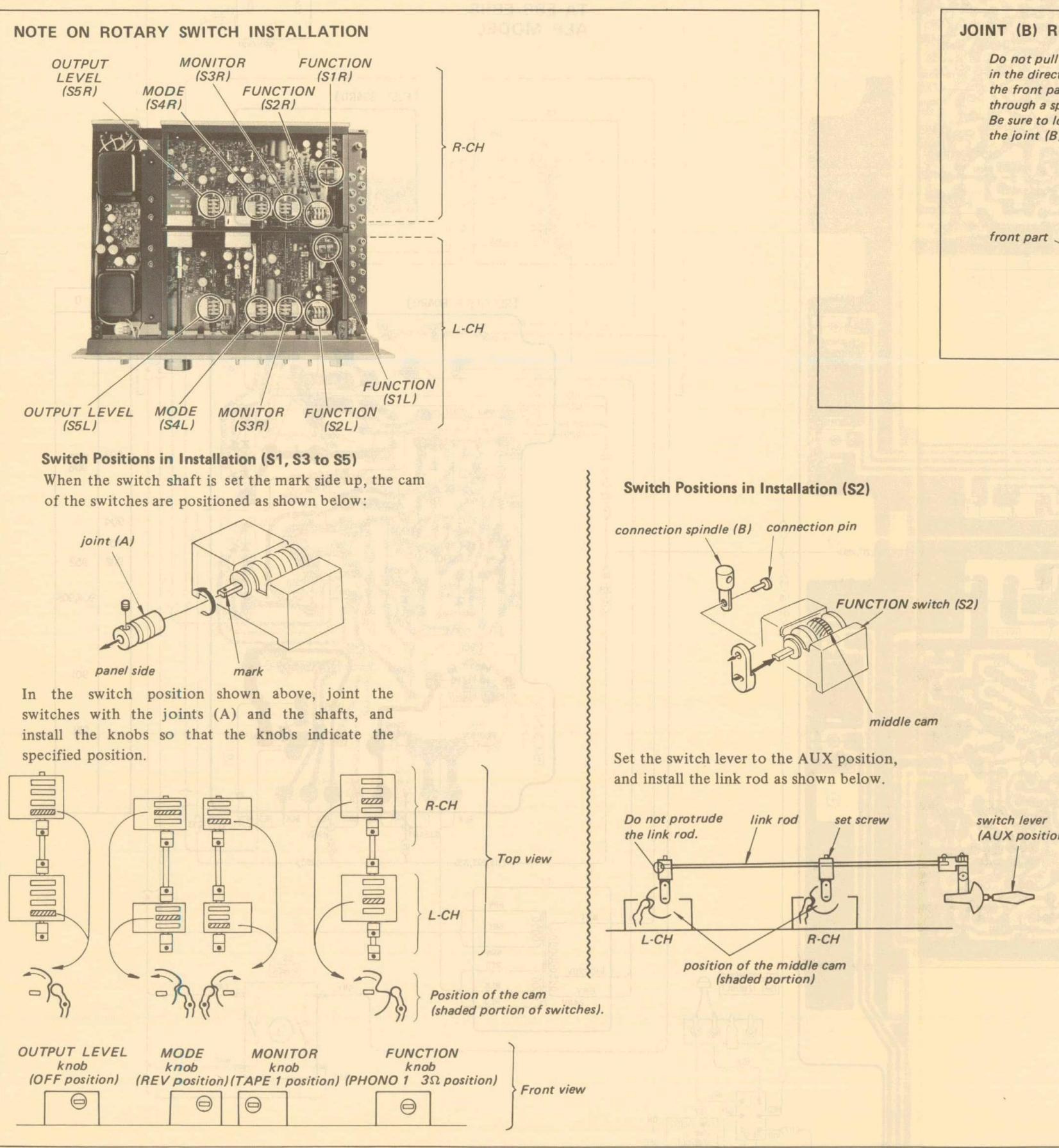
CIRCUIT BOARD CHECKING

*Circuit boards can be repaired without removal.
With electrolytic capacitors near the conductor
side of head amp power supply boards disconnected,
the head amp power supply boards can be checked.*

rectifier board

main board

head amp
power supply
board



SECTION 3 ADJUSTMENTS

OFFSET ADJUSTMENT-1 (PHONO EQ AMP)

Setting:

POWER switch (S6) : ON
FUNCTION switch (S1) : PHONO 1
FUNCTION switch (S2) : PHONO
OUTPUT LEVEL switch (S5) : 0dB

Procedure:

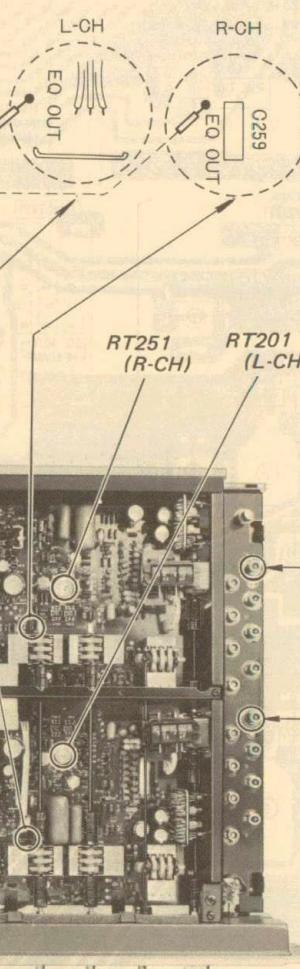
1. Terminate the PHONO 1 jack with a shorting plug.
2. Adjust RT201 (L-CH) and RT251 (R-CH) for 0V reading on VOM.

Specification:

EQ OUT level: $0 \pm 0.1V$

Adjustment Location:

- main board -



OFFSET ADJUSTMENT-2 (OUTPUT AMP)

Setting:

POWER switch (S6) : ON
ATTENUATOR control : fully counter-clockwise
MONITOR switch (S3) : SOURCE
MODE switch (S4) : STEREO
BALANCE control : mechanical mid
ATTENUATOR control : fully clockwise
OUTPUT LEVEL switch (S5) : 0dB

Procedure:

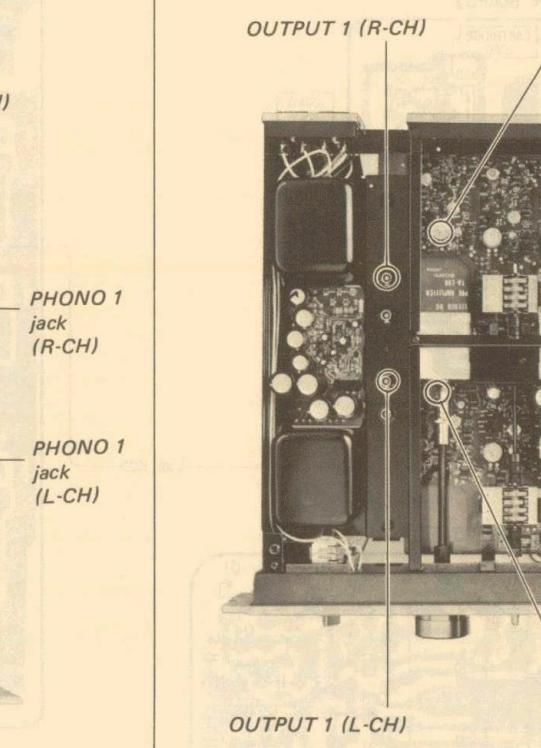
- oscilloscope (dc range, vertical amplifier sensitivity; 1mV/div or less)**
-
- set**
OUTPUT 1 0V dc
1. Adjust RT401 (L-CH) and RT451 (R-CH) for 0V reading on oscilloscope.

Specification:

OUTPUT 1 level: $0 \pm 0.1mV$

Adjustment Location:

- main board -



OFFSET ADJUSTMENT-3 (BUFFER AMP)

Setting:

POWER switch (S6) : ON
FUNCTION switch (S1) : TUNER
MONITOR switch (S3) : SOURCE
MODE switch (S4) : STEREO
BALANCE control : mechanical mid
ATTENUATOR control : fully clockwise
OUTPUT LEVEL switch (S5) : 0dB

Procedure:

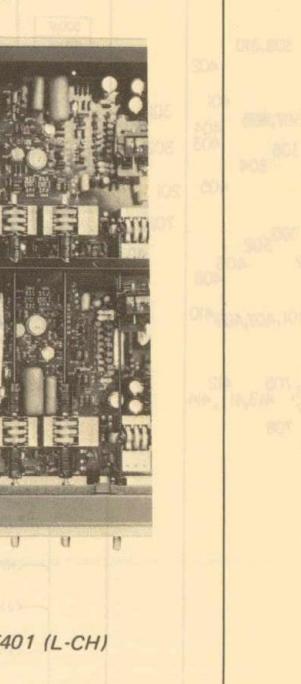
- oscilloscope (dc range, vertical amplifier sensitivity; 1mV/div or less)**
-
- set**
OUTPUT 1 0V dc
1. Terminate the TUNER jack with a shorting plug.
 2. Adjust RT301 (L-CH) and RT351 (R-CH) for 0V reading on oscilloscope.

Specification:

OUTPUT 1 level: $0 \pm 0.1mV$

Adjustment Location:

- main board -



MUTING TIME CHECKING

Confirm the operation of the relays (RY301, 351)

- RY301 and RY351 are energized at about eight seconds after the POWER switch is turned ON.
- RY301 and RY351 are released at the moment when the POWER switch is turned OFF.

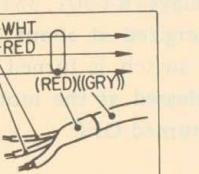
1. Turn the power supply unit to the ON position.
2. Turn the power switch to the ON position.
RY301 and RY351 are energized at about eight seconds after the power switch is turned ON.
RY301 and RY351 are released at the moment when the power switch is turned OFF.

SECTION 4 DIAGRAMS

4-1. MOUNTING DIAGRAM

Conductor Side

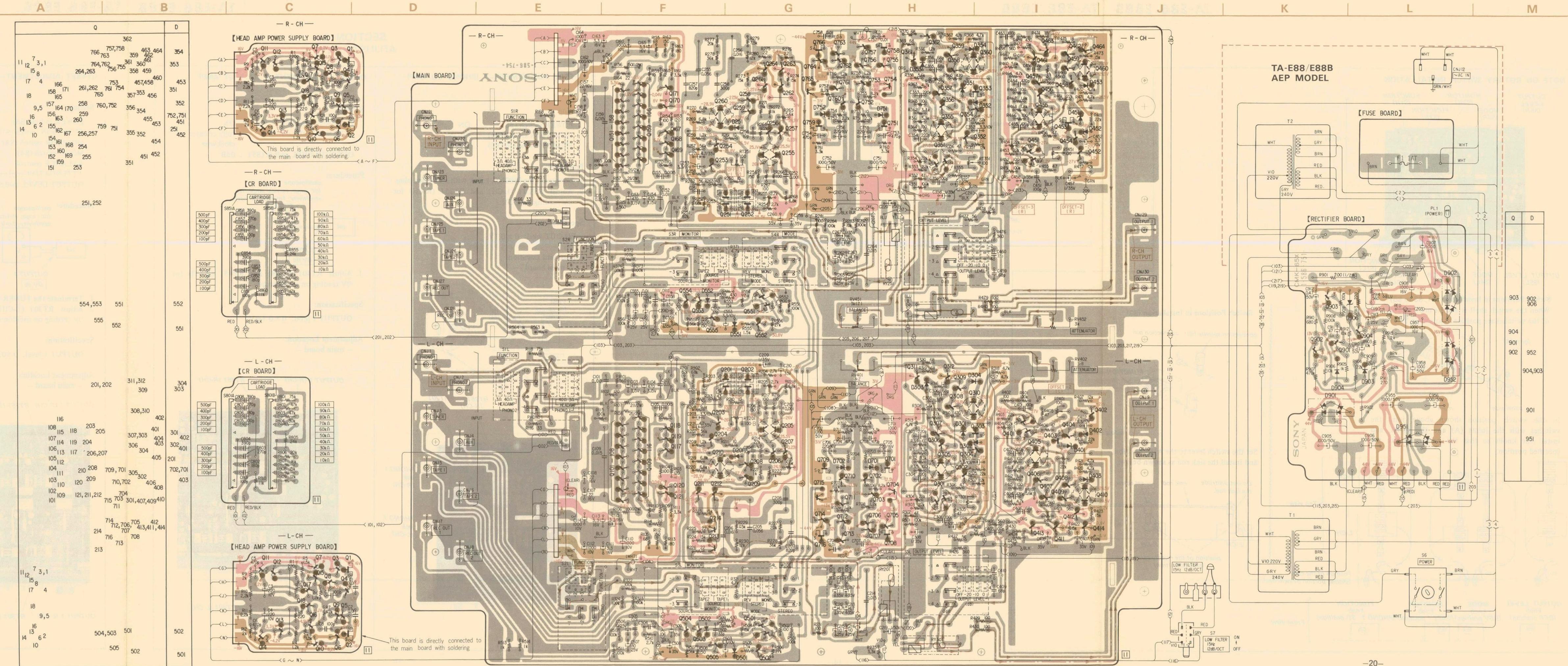
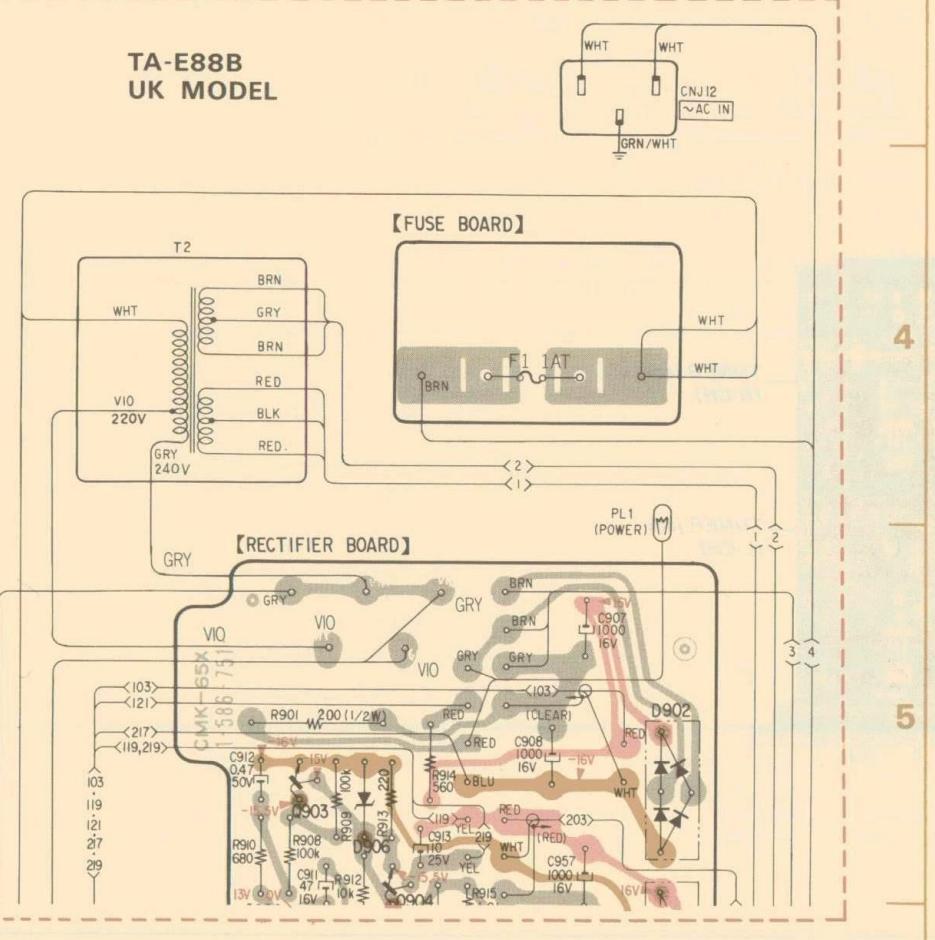
- Color code of sleeving over the end of the jacket.

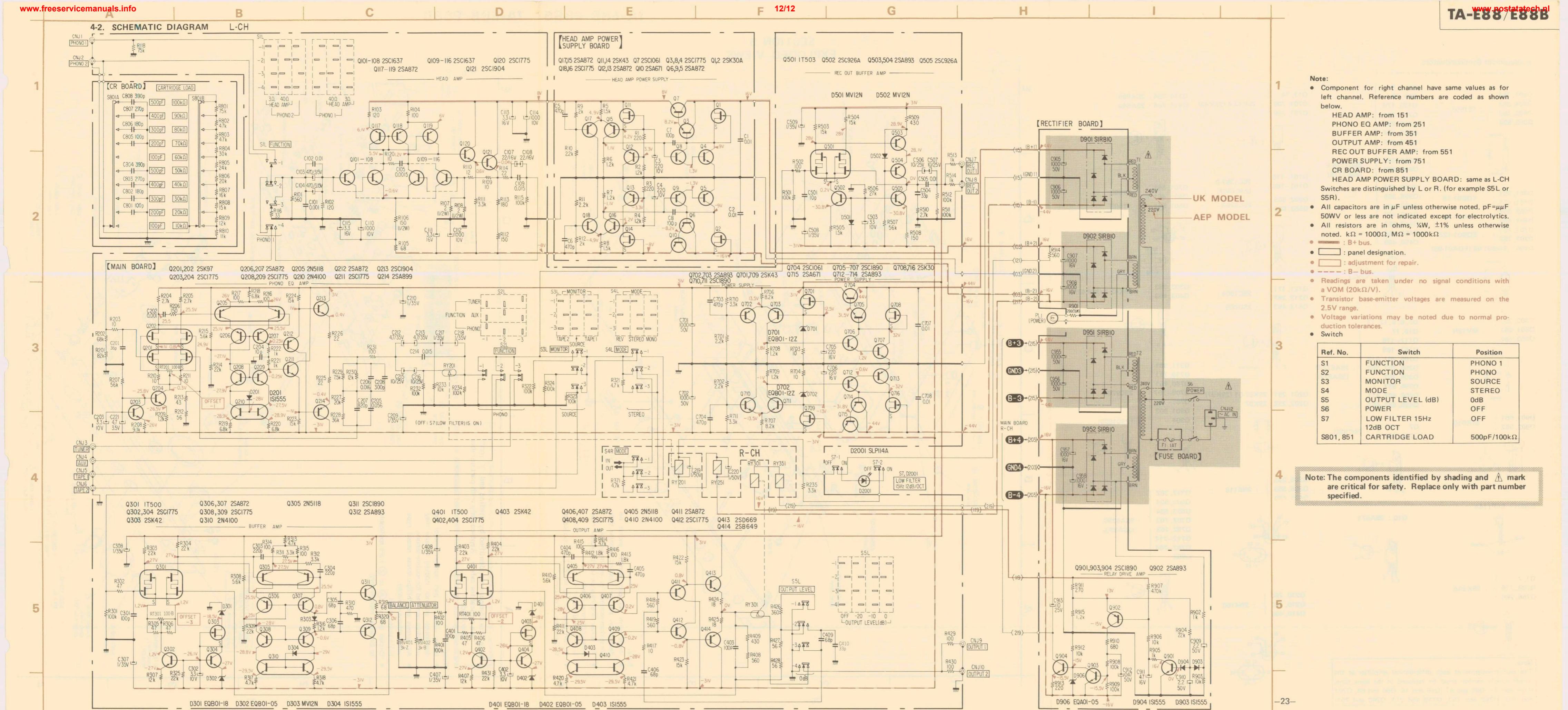


- B+ pattern.
- B- pattern.
- Readings are taken under no signal conditions with a VOM (20kΩ/V).

Note:
The pair transistors of each differential amplifier at the power supply section must be replaced at the same time.
(Q15 and 17, Q65 and 67, Q16 and 18, Q66 and 68, Q701 and 703, Q752 and 753, Q710 and 711, Q760 and 761)

TA-E88B UK MODEL

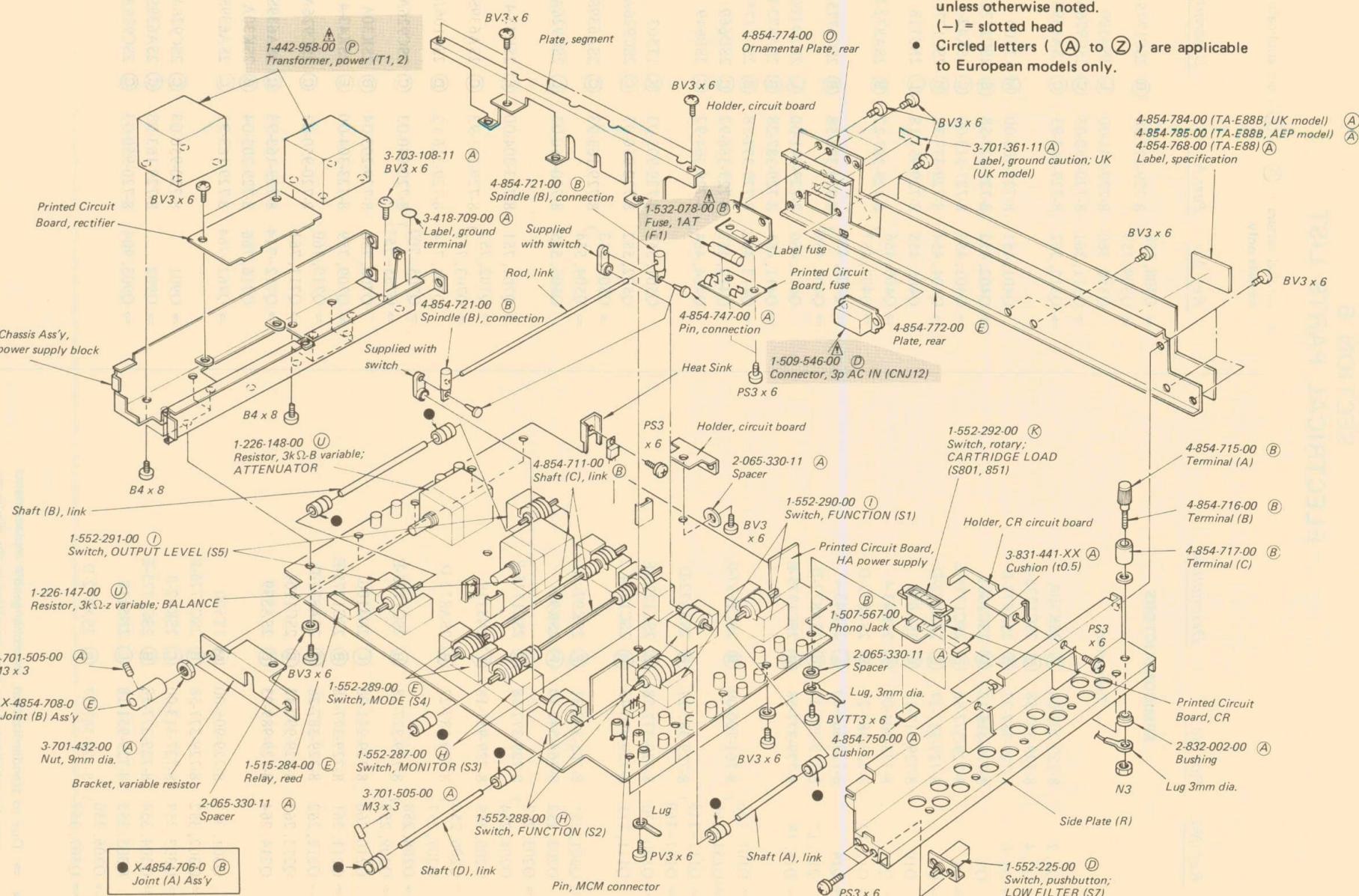




Note: The components identified by shading and mark are critical for safety. Replace only with part number specified.

Note:

- Items with no part number and/or no description are not stocked because they are seldom required for routine service.
- All screws are Phillips (cross recess) type unless otherwise noted.
(-) = slotted head
- Circled letters (Ⓐ to Ⓛ) are applicable to European models only.



SECTION 6

ELECTRICAL PARTS LIST

<u>Ref. No.</u>	<u>Part No.</u>	<u>Description</u>
SEMICONDUCTORS		
Transistors		
Q1, 2	8-729-203-04	(B) 2SK30A
⇒ Q3, 4	8-729-377-58	(B) 2SC1775-E
⇒ Q5, 6	8-729-387-27	(B) 2SA872-D
Q7	8-729-316-12	(D) 2SC1061
⇒ Q8	8-729-377-58	(B) 2SC1775-E
⇒ Q9	8-729-387-27	(B) 2SA872-D
Q10	8-729-317-12	(E) 2SA671
⇒ Q11	8-723-304-00	(E) 2SK43-4
⇒ Q12, 13	8-729-387-27	(B) 2SA872-D
⇒ Q14	8-723-304-00	(E) 2SK43-4
Q15, 17	8-729-387-27	(B) 2SA872-D
⇒ Q16, 18	8-729-377-58	(B) 2SC1775-E
⇒ Q101-106	8-761-700-00	(B) 2SC1637-0
⇒ Q151-166		
⇒ Q117-119	8-729-387-27	(B) 2SA872-D
⇒ Q167-169	8-729-377-58	(B) 2SC1775-E
⇒ Q120, 170	8-729-377-58	(B) 2SC1775-E
Q121, 171	8-729-990-43	(B) 2SC1904
⇒ Q201, 251	8-765-342-31	(F) 2SK97-01
Q202, 252	8-765-342-10	(F) 2SK97
⇒ Q203, 253	8-729-377-58	(B) 2SC1775-E
Q204, 254		
Q205, 255	8-729-951-18	(L) 2N5118
⇒ Q206, 256	8-729-387-27	(B) 2SA872-D
Q207, 257		
⇒ Q208, 258	8-729-377-58	(B) 2SC1775-E
⇒ Q209, 259	8-729-377-58	(B) 2SC1775-E
Q210, 260	8-729-941-00	(L) 2N4100
⇒ Q211, 261	8-729-377-58	(B) 2SC1775-E
⇒ Q212, 262	8-729-387-28	(B) 2SA872-D
Q213, 263	8-729-990-43	(B) 2SC1904
Q214, 264	8-729-989-93	(B) 2SA899
Q301, 351	8-729-905-00	(M) 1T500
⇒ Q302, 352	8-729-377-58	(B) 2SC1775-E
⇒ Q303, 353	8-727-313-00	(C) 2SK42-3
⇒ Q304, 354	8-729-377-58	(B) 2SC1775-E
Q305, 355	8-729-951-18	(L) 2N5118
⇒ Q306, 356	8-729-387-27	(B) 2SA872-D
⇒ Q307, 357		

• ⇒: Due to standardization, interchangeable replacements may be substituted for parts specified in the diagrams.

• Circled letters (A to Z) are applicable to European models only.

<u>Ref. No.</u>	<u>Part No.</u>	<u>Description</u>
Transistors		
⇒ Q308, 358		
⇒ Q309, 359	8-729-377-58	(B) 2SC1775-E
Q310, 360	8-729-941-00	(L) 2N4100
⇒ Q311, 361	8-720-950-03	(C) 2SC926A
⇒ Q312, 362	8-729-163-93	(C) 2SA639S
Q401, 451	8-729-905-00	(M) 1T500
⇒ Q402, 452	8-729-377-58	(B) 2SC1775-E
⇒ Q403, 453	8-727-313-00	(C) 2SK42-3
⇒ Q404, 454	8-729-377-58	(B) 2SC1775-E
Q405, 455	8-729-951-18	(L) 2N5118
⇒ Q406, 456	8-729-387-27	(B) 2SA872-D
⇒ Q407, 457		
⇒ Q408, 458	8-729-377-58	(B) 2SC1775-E
⇒ Q409, 459	8-729-377-58	(B) 2SC1775-E
Q410, 460	8-729-941-00	(L) 2NA4100
⇒ Q411, 461	8-729-387-28	(B) 2SA872-D
⇒ Q412, 462	8-729-377-58	(B) 2SC1775-E
Q413, 463	8-729-366-92	(C) 2SD669
Q414, 464	8-729-364-92	(C) 2SB649
Q501, 551	8-729-905-03	(K) 1T503
Q502, 552	8-720-950-03	(C) 2SC926A
⇒ Q503, 553	8-729-163-93	(C) 2SA639S
⇒ Q504, 554		
Q505, 555	8-720-950-03	(C) 2SC926A
⇒ Q701, 751	8-723-304-00	(E) 2SK43-4
⇒ Q702, 752		
⇒ Q703, 753	8-729-163-93	(C) 2SA639S
Q704, 754	8-729-316-12	(D) 2SC1061
⇒ Q705-707	8-720-950-03	(C) 2SC926A
⇒ Q755-757		
Q708, 758	8-729-203-04	(B) 2SK30A
⇒ Q709, 759	8-723-304-00	(E) 2SK43-4
⇒ Q710, 760		
⇒ Q711, 761	8-720-950-03	(C) 2SC926A
⇒ Q712-714	8-729-163-93	(C) 2SA639S
Q716, 766	8-729-203-04	(B) 2SK30A
⇒ Q762-764	8-729-163-93	(C) 2SA639S
⇒ Q901	8-720-950-03	(C) 2SC926A
⇒ Q902	8-729-163-93	(C) 2SA639S
⇒ Q903, 904	8-720-950-03	(C) 2SC926A

<u>Ref. No.</u>	<u>Part No.</u>	<u>Description</u>	<u>Ref. No.</u>	<u>Part No.</u>	<u>Description</u>
Diodes					
D201, 251					
D201, 251	8-719-815-55	(B) 1S1555	C111, 161	1-131-449-11	(C) 3.3 16V tantalum
D301, 351	8-719-931-18	(B) EQB01-18	C112, 162	1-121-736-11	(B) 1000 10V elect
D302, 352	8-719-931-05	(B) EQB01-05	C113, 163	1-131-449-11	(C) 3.3 16V tantalum
D303, 353	8-719-912-00	(B) MV12N	C114, 164	1-121-736-11	(B) 1000 10V elect
D304, 354	8-719-815-55	(B) 1S1555	C115, 165	1-131-449-11	(C) 3.3 16V tantalum
D401, 451	8-719-931-18	(B) EQB01-18	C201, 251	1-102-890-11	(A) 36p
D402, 452	8-719-931-05	(B) EQB01-05	C202, 252	1-102-074-11	(A) 0.001
D403, 453	8-719-815-55	(B) 1S1555	C203, 253	1-131-449-11	(C) 3.3 16V tantalum
D501, 551	8-719-912-00	(B) MV12N	C204, 254	1-102-947-11	(A) 10p
D502, 552			C205, 255	1-130-146-11	(C) 0.056 2% polyethylene
D701, 751	8-719-930-12	(B) EQB01-12Z	C206, 256	1-130-145-11	(B) 0.016 2% polyethylene
D702, 752			C207, 257	1-103-723-11	(B) 820p 5% polystyrol
D901, 951	8-719-510-10	(C) SIRB10	C208, 258	1-103-712-11	(A) 330p 5% polystyrol
D902, 952			C209, 259	1-131-450-11	(C) 1 35V tantalum
D903, 904	8-719-815-55	(B) 1S1555	C210, 260		
⇒ D906	8-719-931-05	(B) EQB01-05	C212, 262	1-131-219-11	(B) 4.7 35V tantalum
D2001	8-719-921-14	(B) SLP-114A	C213, 263	1-104-129-11	(C) 0.015
Transformers					
T1, 2	△ 1-442-958-00	(P) Power	C214, 264	1-104-129-11	(C) 0.015
CAPACITORS					
All capacitors are in μF and ceramic unless otherwise noted. 50WV or less are not indicated except for electrolytics. $\text{pF} = \mu\text{F}$, elect = electrolytic					
C1, 2	1-101-118-11	(A) 0.01	C301, 351	1-102-973-11	(A) 100p
C3, 4	1-121-420-11	(B) 220 10V elect	C302, 352	1-131-449-11	(C) 3.3 16V tantalum
C5, 6	1-102-114-11	(A) 470p	C303, 353	1-102-110-11	(A) 220p
C7, 8	1-102-973-11	(A) 100p	C304, 354	1-101-888-11	(A) 68p
C101, 151	1-102-074-11	(A) 0.001	C305, 355	1-101-888-11	(A) 68p
C102, 152	1-130-127-11	(B) 0.015 100V polyethylene	C306, 356	1-131-450-11	(C) 1 35V tantalum
C103, 153	1-131-429-11	(G) 470 3.15V tantalum	C307, 357	1-102-114-11	(A) 470p
C104, 154			C308, 358	1-102-114-11	(A) 470

Manual of instructions for TA-E88/E88B electronic vacuum cleaner
Vine version

Note: Circled letters (Ⓐ to Ⓛ) are applicable to European models only.

Ref. No.	Part No.	Description
C407, 457	1-131-450-11	Ⓐ 1 35V tantalum
C408, 458		
C409, 459	1-101-888-11	Ⓐ 68p
C410, 460	1-102-963-11	Ⓐ 33p
C501, 551	1-102-947-11	Ⓐ 10p
C503, 553	1-131-449-11	Ⓒ 3.3 16V tantalum
C504, 554	1-102-963-11	Ⓐ 33p
C505, 555	1-102-129-11	Ⓐ 0.01
C506, 556	1-131-238-11	Ⓑ 10 25V tantalum
C507, 557		
C508, 558	1-131-450-11	Ⓒ 1 35V tantalum
C509, 559		
C701, 751	1-123-061-11	Ⓒ 1000 50V elect
C702, 752		
C703, 753	1-102-114-11	Ⓐ 470p
C704, 754		
C705, 755	1-121-421-11	Ⓑ 220 16V elect
C706, 756		
C707, 757	1-101-118-11	Ⓐ 0.01
C708, 758		
C801	1-102-106-11	Ⓐ 100p
C802	1-102-109-11	Ⓐ 180p
C803	1-102-111-11	Ⓐ 270p
C804	1-102-113-11	Ⓐ 390p
C805	1-102-106-11	Ⓐ 100p
C806	1-102-109-11	Ⓐ 180p
C807	1-102-111-11	Ⓐ 270p
C808	1-102-113-11	Ⓐ 390p
C905, 955	△1-123-061-11	Ⓒ 1000 50V elect
C906, 956		
C907, 957		
C908, 958	△1-121-944-11	Ⓔ 1000 16V elect
C909, 910	1-121-450-11	Ⓐ 2.2 50V elect
C911	1-121-409-11	Ⓐ 47 16V elect
C912	1-121-726-11	Ⓐ 0.47 50V elect
C913	1-121-398-11	Ⓐ 10 25V elect

Note: The components identified by shading and ⚠ mark are critical for safety. Replace only with part number specified.

Ref. No.	Part No.	Description
RESISTORS		
		All resistors are in ohms and of 1/4W metal oxide unless otherwise noted.
R1	1-214-116-11	Ⓑ 220
R2	1-214-134-11	Ⓑ 1.2k
R3	1-214-116-11	Ⓑ 220
R4	1-214-134-11	Ⓑ 1.2k
R5	1-214-136-11	Ⓑ 1.5k
R6, 7	1-214-134-11	Ⓑ 1.2k
R8	1-214-136-11	Ⓑ 1.5k
R9	1-214-139-11	Ⓑ 2k
R10, 11	1-214-140-11	Ⓑ 2.2k
R12	1-214-139-11	Ⓑ 2k
R101, 151	1-214-126-11	Ⓑ 560
R102, 152		
R103, 153	1-214-110-11	Ⓑ 120
R104, 154	1-214-108-11	Ⓑ 100
R105, 155	1-214-104-11	Ⓑ 68
R106, 156	1-244-853-11	Ⓐ 150 1/2W carbon
R107, 157	1-244-808-11	Ⓐ 2 1/2W carbon
R108, 158		
R109, 159	1-214-084-11	Ⓑ 10
R110, 160	1-214-086-11	Ⓑ 12
R111, 161	1-214-144-11	Ⓑ 3.3k
R112, 162	1-214-112-11	Ⓑ 150
R113, 163	1-214-114-11	Ⓑ 180
R114, 164	1-214-092-11	Ⓑ 22
R115, 165	1-214-180-11	Ⓑ 100k
R116, 166	1-214-096-11	Ⓑ 33
R118, 168	1-214-177-11	Ⓑ 75k
R120, 170	1-214-084-11	Ⓑ 10
R201, 251	1-214-178-11	Ⓑ 82k
R202, 252	1-214-176-11	Ⓐ 68k
R203, 253	1-214-084-11	Ⓑ 10
R204, 254	1-214-142-11	Ⓑ 2.7k
R205, 255		
R206, 256	1-214-112-11	Ⓑ 150
R207, 257	1-214-174-11	Ⓐ 56k

Ref. No.	Part No.	Description
R208, 258	1-214-157-11	Ⓑ 11k
R209, 259	1-214-134-11	Ⓑ 1.2k
R210, 260	1-214-084-11	Ⓑ 10
R211, 261		
R212, 262	1-214-102-11	Ⓑ 56
R213, 263	1-214-099-11	Ⓑ 43
R214, 264	1-214-164-11	Ⓑ 22k
R215, 265	1-214-150-11	Ⓑ 5.6k
R216, 266	1-214-108-11	Ⓑ 100
R217, 267		
R218-220		
R268-270	1-214-152-11	Ⓑ 6.8k
R221, 271	1-214-132-11	Ⓑ 1k
R222, 272		
R223, 273	1-214-160-11	Ⓑ 15k
R224, 274		
R225, 275	1-214-092-11	Ⓑ 22
R226, 276		
R227, 277	1-214-163-11	Ⓑ 20k
R228, 278	1-214-169-11	Ⓑ 36k
R229, 279	1-214-153-11	Ⓑ 7.5k
R230, 280	1-214-158-11	Ⓑ 12k
R231, 281	1-214-108-11	Ⓑ 100
R232, 282	1-214-180-11	Ⓑ 100k
R233, 283	1-214-156-11	Ⓑ 10k
R234, 284	1-214-180-11	Ⓑ 100k
R301, 351	1-214-180-11	Ⓑ 100k
R302, 352	1-214-100-11	Ⓑ 47
R303, 353	1-214-164-11	Ⓑ 22k
R304, 354		
R305, 355	1-214-100-11	Ⓑ 47
R306, 356		
R307, 357	1-214-158-11	Ⓑ 12k
R308, 358	1-214-150-11	Ⓑ 5.6k
R309, 359	1-214-164-11	Ⓑ 22k
R310, 360	1-214-124-11	Ⓑ 470
R311, 361	1-214-144-11	Ⓑ 3.3k
R312, 362		
R313, 363	1-214-148-11	Ⓑ 47k
R314, 364	1-214-108-11	Ⓑ 100
R315, 365		

Ref. No.	Part No.	Description
R316, 366	1-214-134-11	Ⓑ 1.2k
R317, 367	1-214-148-11	Ⓑ 4.7k
R318, 368		
R319, 369	1-214-104-11	Ⓑ 68
R320, 370		
R321, 371	1-214-148-11	Ⓑ 4.7k
R322-324	1-214-180-11	Ⓑ 100k
R372-374		
R325, 375	1-214-164-11	Ⓑ 22k
R401, 451	1-214-180-11	Ⓑ 100k
R402, 452	1-214-108-11	Ⓑ 100
R403, 453	1-214-164-11	Ⓑ 22k
R404, 454		
R405, 455	1-214-100-11	Ⓑ 47
R406, 456		
R407, 457	1-214-158-11	Ⓑ 12k
R408, 458	1-214-126-11	Ⓑ 560
R409, 459	1-214-123-11	Ⓑ 430
R410, 460	1-214-150-11	Ⓑ 5.6k
R411, 461	1-214-164-11	Ⓑ 22k
R412, 462	1-214-138-11	Ⓑ 1.8k
R413, 463		
R414, 464	1-214-148-11	Ⓑ 4.7k
R415, 465	1-214-108-11	Ⓑ 100
R416, 466		
R417, 467	1-214-084-11	Ⓑ 10
R418, 468	1-214-126-11	Ⓑ 560
R419, 469		
R420, 470	1-214-148-11	Ⓑ 4.7k
R421, 471		
R422, 472	1-214-160-11	Ⓑ 15k
R423, 473		
R424, 474	1-214-090-11	Ⓑ 18
R425, 475		
R426, 476	1-214-121-11	Ⓑ 360
R427, 477	1-214-102-11	Ⓑ 56
R428, 478		
R429, 479	1-214-108-11	Ⓑ 100
R430, 480	1-214-164-11	Ⓑ 22k
R431, 481		

TA-E88/E88B

Note: Circled letters (Ⓐ to Ⓛ) are applicable to European models only.

Ref. No.	Part No.	Description
R501, 551	1-214-180-11	(B) 100k
R502, 552	1-214-108-11	(B) 100
R503, 553	1-214-160-11	(B) 15k
R504, 554	1-214-136-11	(B) 1.5k
R505, 555	1-214-166-11	(B) 27k
R506, 556	1-214-174-11	(B) 56k
R507, 557	1-214-112-11	(B) 150
R508, 558	1-214-123-11	(B) 430
R509, 559	1-214-142-11	(B) 2.7k
R510, 560	1-214-180-11	(B) 100k
R511, 561	1-214-132-11	(B) 1k
R512, 562	1-214-140-11	(B) 2.2k
R513, 563	1-214-084-11	(B) 10
R514, 564	1-214-154-11	(B) 8.2k
R701, 751	1-214-134-11	(B) 1.2k
R702, 752	1-214-144-11	(B) 3.3k
R703, 753	1-214-177-11	(B) 75k
R704, 754	1-214-172-11	(B) 47k
R705, 755	1-214-167-11	(B) 30k
R706, 756	1-214-165-11	(B) 24k
R707, 757	1-214-163-11	(B) 20k
R801	1-214-158-11	(B) 16k
R802, 803	1-214-157-11	(B) 15k
R804	1-214-151-11	(B) 12k
R805	1-214-152-11	(B) 11k
R806	1-226-149-00	(F) 100-Z, adjustable
R807	1-244-856-11	(A) 200Ω ½W carbon
R808	1-214-134-11	(B) 1.2k
RT201, 251	1-226-147-00	(U) 3k-Z, variable; BALANCE
RT301, 351	1-226-148-00	(U) 3k-B, variable; ATTENUATOR
RT401, 451		
RV401, 451	1-226-147-00	(U) 3k-Z, variable; BALANCE
RV402, 452	1-226-148-00	(U) 3k-B, variable; ATTENUATOR